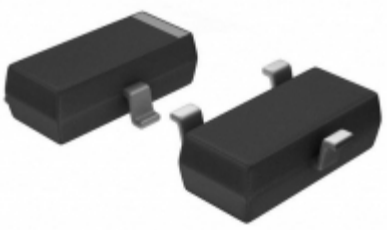

	<p>SI2304BDS-T1-E3</p>
	<p>Hersteller-Teilenummer: SI2304BDS-T1-E3</p>
	<p>Hersteller / Marke: Vishay / Siliconix</p>
	<p>Teil der Beschreibung: MOSFET N-CH 30V 2.6A SOT23-3</p>
<p>Datenblätter:  SI2304BDS-T1-E3.pdf</p>	<p>RoHs Status: Bleifrei / RoHS-konform</p>
<p>Lagerzustand: New original, 370907 pcs Stock Available.</p>	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI2304BDS-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 2.6A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	370907 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	750mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.6A (Ta)
Rds On (Max) @ Id, Vgs	70 mOhm @ 2.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	225pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SI2304BDS-T1-E3 ist neu im Original, Suche SI2304BDS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2304BDS-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2304BDS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2304BDS-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 2.6A SOT23-3</p>	 <p>SI2304CDS-T1-E3 VISHAY VISHAY SOT-23</p>	 <p>SI2304BDS-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.6A SOT23-3</p>	 <p>SI2304-TP Micro Commercial Components (MCC) N-CHANNEL MOSFET, SOT-23 PACKAGE</p>
 <p>SI2304BDS-TI-E3 VISHAY SI2304BDS-TI-E3 VISHAY</p>	 <p>SI2304(A69T) Original SOT-23</p>	 <p>SI2304BDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.6A SOT23-3</p>	 <p>SI2304BDS VISHAY SI2304BDS VISHAY</p>

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|--|--|---|--|---|
| <ul style="list-style-type: none"> ⊕ SI2302DS-T1-GE3 ⊖ SI2303BDS-T ⊕ SI2303BDS-T1-GE3 D SI2303CDS-T1-E3 ➔ SI2303DS-T1 ➔ SI2304BDS-T1-GE3 ⊕ SI2304DDS-T1-GE3 ⊖ SI2305-CDS-T1-GE3 ⊕ SI2305BDS-T1-E3 ➔ SI2305DS | <ul style="list-style-type: none"> ➔ SI2302DV ⊕ SI2303BDS-T1 ⊖ SI2303BDS-T1-GE3 ⊕ SI2303CDS-T1-GE3 ➔ SI2303DS-T1-E3 ➔ SI2304BDS-T1-GE3 D SI2304DS ⊕ SI2305ADS-T1-E3 ⊖ SI2305BDS-T1-GE3 ⊕ SI2305DS-E3 | <ul style="list-style-type: none"> ➔ SI2302WCB D SI2303BDS-T1 ⊕ SI2303BDS/A5 ⊖ SI2303CDS-T1-GE3 ⊕ SI2303DS-T1-GE3 D SI2304BDS-TI-E3 ➔ SI2304DS-T1 ➔ SI2305ADS-T1-E3 ⊕ SI2305CDS-T1-E3 ⊖ SI2305DS-T1 | <ul style="list-style-type: none"> D SI2303ADS-T1-GE3 ➔ SI2303BDS-T1-E3 ➔ SI2303CDS ⊕ SI2303DL-T1-E3 ⊖ SI2304-TP ⊕ SI2304DDS-T1-E3 ➔ SI2304DS-T1-E3 ➔ SI2305ADS-T1-GE3 D SI2305CDS-T1-GE3 ⊕ SI2305DS-T1-E3 | <ul style="list-style-type: none"> ➔ SI2303BDS ➔ SI2303BDS-T1-E3 ➔ SI2303CDS-T1-E3 ➔ SI2303DS ➔ SI2304BDS-T1-E3 ⊖ SI2304DDS-T1-GE3 ➔ SI2304DS-T1-GE3 ➔ SI2305ADS-T1-GE3 ➔ SI2305CDS-T1-GE3 ➔ SI2305DS-T1-E3 |
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Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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